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1N91x, 1N4x48, FDLL914, FDLL4x48

ABSOLUTE MAXIMUM RATINGS (Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted) (Note 1)

Rating	Symbol	Value	Unit	
Maximum Repetitive Reverse Voltage	V_{RRM}	100	V	
Average Rectified Forward Current	I_O	200	mA	
DC Forward Current	I_F	300	mA	
Recurrent Peak Forward Current	I_f	400	mA	
Non-repetitive Peak Forward Surge Current		Pulse Width = 1.0 s	1.0	A
		Pulse Width = 1.0 μs	4.0	A
Storage Temperature Range	T_{STG}	-65 to +200	$^\circ\text{C}$	
Operating Junction Temperature Range	T_J	-55 to +175	$^\circ\text{C}$	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are limiting values above which the serviceability of the diode may be impaired.

THERMAL CHARACTERISTICS

Parameter	Symbol	Max	Unit
Power Dissipation	P_D	500	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	300	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS (Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted) (Note 2)

Symbol	Parameter	Conditions	Min	Max	Unit	
V_R	Breakdown Voltage	$I_R = 100 \mu\text{A}$	100		V	
		$I_R = 5.0 \mu\text{A}$	75		V	
V_F	Forward Voltage	914B / 4448	$I_F = 5.0 \text{ mA}$	0.62	0.72	V
		916B	$I_F = 5.0 \text{ mA}$	0.63	0.73	V
		914 / 916 / 4148	$I_F = 10 \text{ mA}$		1.0	V
		914A / 916A	$I_F = 20 \text{ mA}$		1.0	V
		916B	$I_F = 20 \text{ mA}$		1.0	V
		914B / 4448	$I_F = 100 \text{ mA}$		1.0	V
I_R	Reverse Leakage	$V_R = 20 \text{ V}$		0.025	μA	
		$V_R = 20 \text{ V}, T_A = 150^\circ\text{C}$		50	μA	
		$V_R = 75 \text{ V}$		5.0	μA	

1N91x, 1N4x48, FDLL914, FDLL4x48

TYPICAL PERFORMANCE CHARACTERISTICS

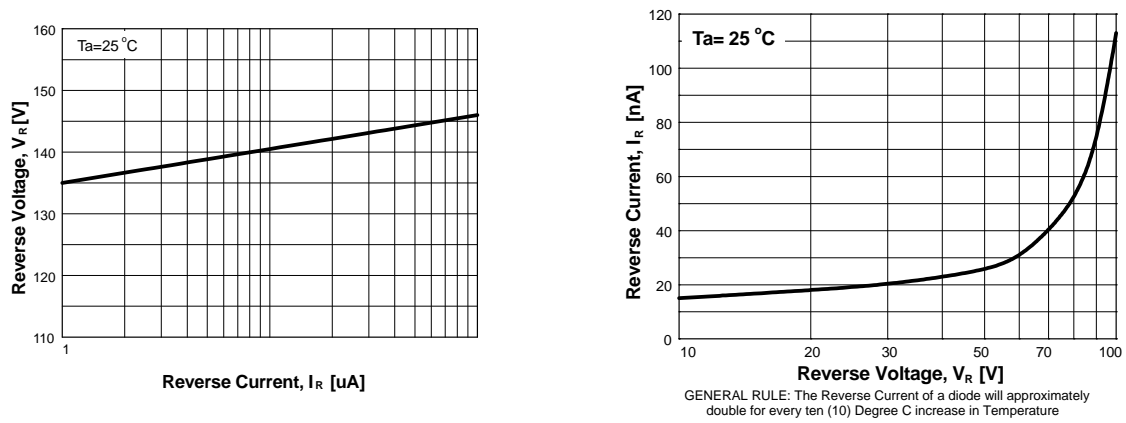


Figure 1. Reverse Voltage vs. Reverse Current
 $B_V - 1.0$ to $100 \mu\text{A}$

1N91x, 1N4x48, FDLL914, FDLL4x48

TYPICAL PERFORMANCE CHARACTERISTICS

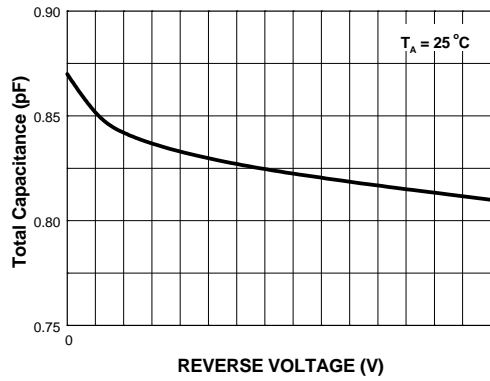


Figure 7. Total Capacitance

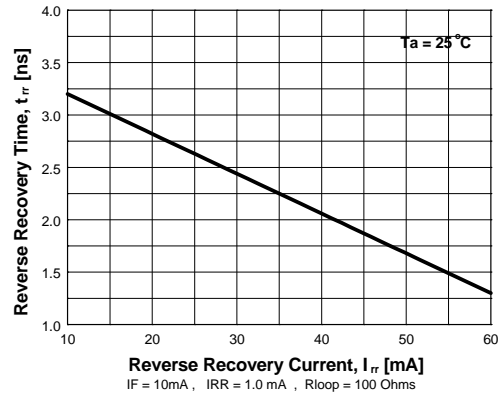
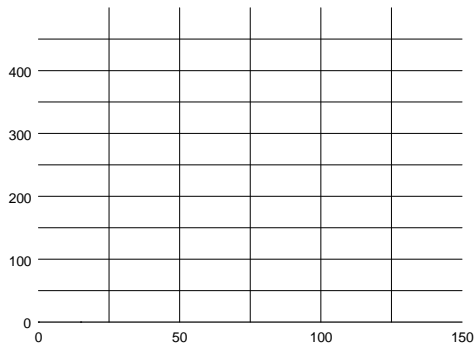


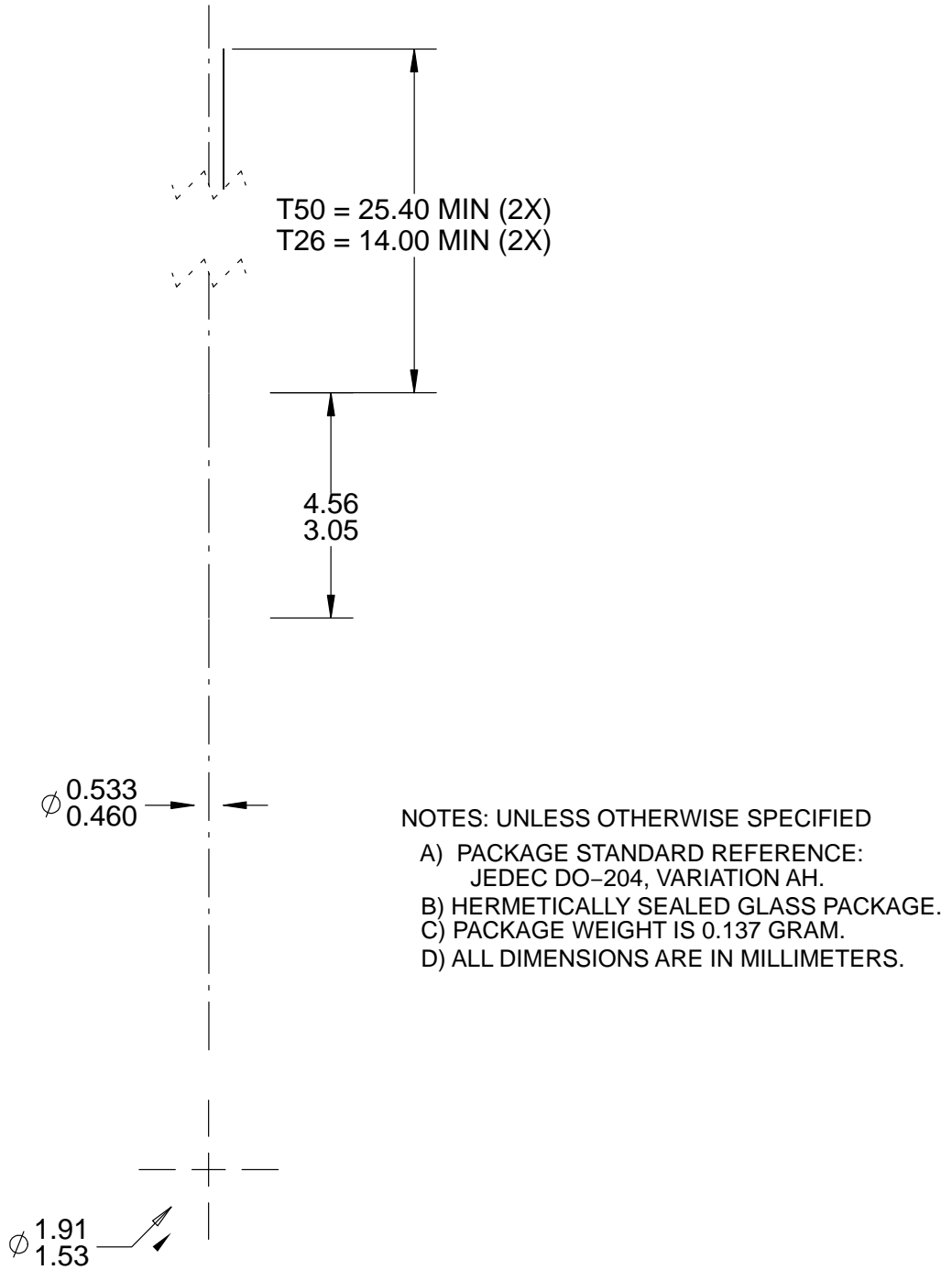
Figure 8. Reverse Recovery Time vs. Reverse Recovery Current





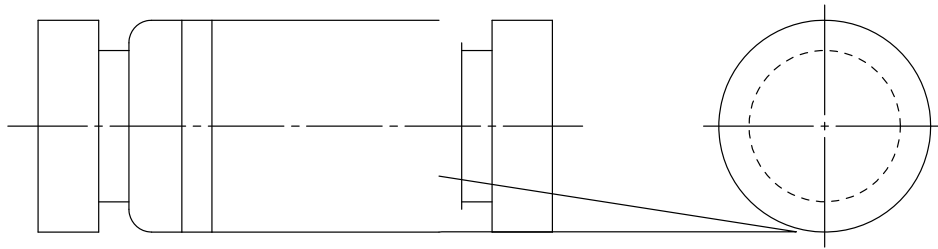
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CASE 017AG
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MiniMELF / SOD 80
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ISSUE 0

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